



mobility of metal atoms.<sup>29,30</sup> In order to address this issue, graphene has emerged as a promising alternative substrate for constructing non-covalent molecular junctions, utilizing anchor groups such as pyrene<sup>31,32</sup> or amine<sup>33,34</sup> to form self-assembled monolayers (SAMs). In comparison to their metal-thiolate counterparts, these graphene/molecule SAMs exhibit improved performance characteristics, including enhanced electric barrier behavior<sup>34</sup> and superior thermoelectric properties.<sup>35</sup>

Most of the recently published graphene/molecule SAMs utilize alkyl chains as the molecular backbone. However, this type of backbone is not preferred in device applications due to its large HOMO–LUMO gap, which suppresses electron transport<sup>36,37</sup> and thermopower.<sup>38</sup> In order to overcome this limitation, molecules with conjugated systems, such as oligo-phenyl structures, are more attractive for molecular thermoelectric studies. Another issue that arises when scaling up single-molecule junctions to SAMs is the introduction of intermolecular interactions between the molecular backbones and their closely packed neighbors. These inter-backbone cross talks are known to have a strong influence on the measured quantum transport and thermoelectric behavior of SAMs.<sup>38,39</sup> For instance, the broadening of the density of states resulting from intermolecular interactions leads to an increase in the width of the highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) resonances, consequently reducing the efficiency of thermoelectric conversion;<sup>39</sup> prolonged exposure to light radiation can induce cross-linking between the polyaromatic molecular backbone and its neighboring species, thereby disrupting the conjugation within self-assembled monolayers (SAMs);<sup>40</sup> the intermolecular coupling opens additional tunneling path for electron transport, and this will quench the single molecule transport behaviour.<sup>41</sup>

Stepwise assembly represents an effective strategy for the formation of highly ordered molecular arrays on various types of substrates and has shown potential in addressing the aforementioned cross-talking issues. Morgado *et al.* utilized a zinc-centered porphyrin footprint and bipyridine wire to construct a supramolecular structure with a length of up to 14 nm on a highly oriented pyrolytic graphite (HOPG) substrate.<sup>42</sup> Cea *et al.* described a layer-by-layer (LBL) approach to generate well-separated arrays of molecular backbones using zinc-centred porphyrin footprint and amine anchored molecular wire on gold substrate, which minimized the intermolecular interactions by the large intermolecular distance.<sup>43</sup> In this study, we employed a similar approach to fabricate well-spaced arrays of oligo-phenyl wires on a single-layered (SL) graphene substrate. Firstly, zinc tetraphenyl porphyrin (ZnTPP, molecule 4 in Fig. 1(a)) was employed for the growth of a molecular thin film on SL chemical-vapor-deposited (CVD) graphene on a copper substrate. The immobilization of ZnTPP molecules on graphene was achieved through  $\pi$ – $\pi$  stacking interactions (Fig. S47(b), ESI† denoted as Gr/4 in later text).<sup>44,45</sup> Secondly, conjugated pyridine backbone molecules (molecules 5, 6, and 7 in Fig. 1(a)) were deposited onto the ZnTPP layer *via* zinc-pyridine coordinative bonds (Fig. 1(d), denotes as Gr/4/X where X denotes molecules 5–7) or (bilayers in later text). These backbones

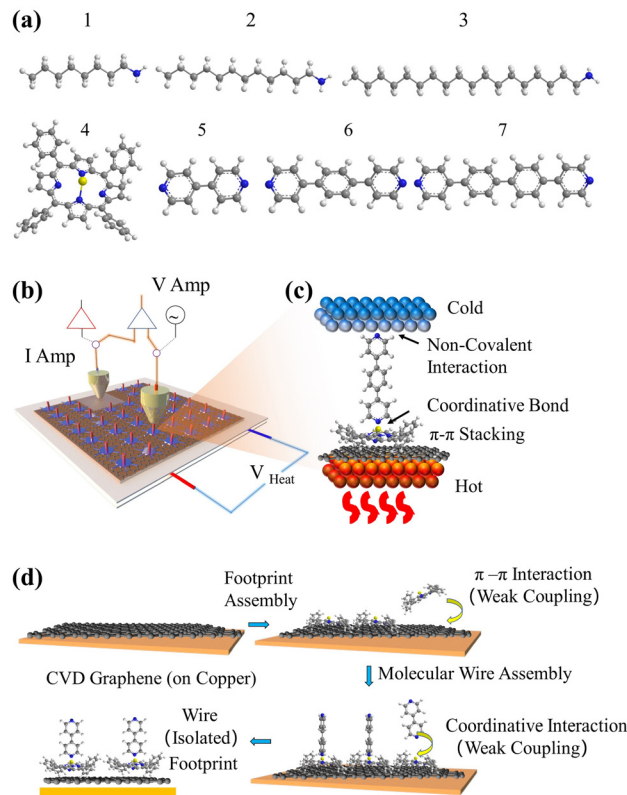


Fig. 1 (a) 7 compounds used to construct SAMs, (b) scheme of measurement system used in this work, (c) an example of multi-component structure in EGaIn junction, and (d) the stepwise assembly strategy of forming molecular arrays.

exhibited a perpendicular orientation with respect to the substrate due to their lone pair geometry and were isolated from each other by the large footprint of ZnTPP molecules (illustration in Fig. 1(b), AFM image in Fig. S47(c)–(e), ESI†).<sup>14,46</sup> The thickness of both the ZnTPP layer and the bilayer self-assembled monolayers (SAMs) on graphene were estimated using the atomic force microscopy (AFM) technique, as illustrated in Fig. S48(a)–(d) (ESI†). The measured results obtained from AFM were found to be in good agreement with the corresponding thickness values estimated using density functional theory (DFT, Fig. S48(e), ESI†). This concordance between experimental and theoretical approaches further validates the bilayer growth. For comparative analysis, this work also investigated a series of alkyl amine molecules known to form high-quality self-assembled monolayers (SAMs) on graphene *via* non-covalent interactions (denote as Gr/X (X: 1–3)), as previously reported.<sup>33,34</sup> These systems exhibit film thicknesses comparable to those of the stepwise assembled structures (Fig. 2), and the hydrophobic force between the alkyl backbones restricts the rotational degree of freedom of the SP3 carbon in the alkyl chain, thereby confirming the molecular configuration.<sup>47</sup>

### Electron transport investigation

The electrical properties of self-assembled monolayers (SAMs) on graphene were investigated by constructing molecular junctions using eutectic Gallium Indium alloy (EGaIn) as the top



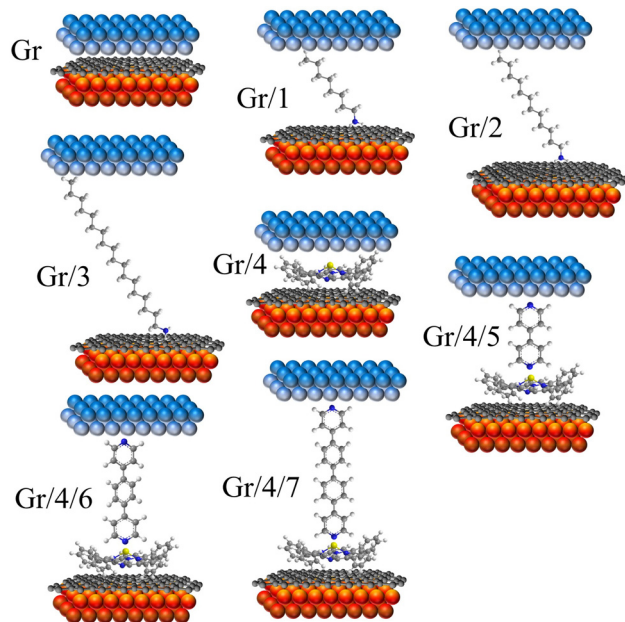


Fig. 2 8 junctions studied in this work. Monolayers including: Gr, Gr/1, Gr/2, Gr/3 and Gr/4. Bilayers including Gr/4/5, Gr/4/6 and Gr/4/7.

electrode.<sup>48</sup> EGaIn is a moldable non-Newtonian liquid metal. In this study, it was shaped into a cone-shaped tip, and the tip retained its shape due to the formation of a  $\sim 0.7$  nm native oxide outer shell (GaOx) upon contact with air.<sup>49,50</sup> It has been proved that this type of tip can contact non-destructively with SAMs<sup>4,8–52</sup> and form Cu/Gr/SAMs/GaOx/EGaIn junction.

Fig. S51(a) (ESI<sup>†</sup>) depicts semi-log plots of current density versus bias voltage ( $J$ - $V$ ) curves for a series of Cu/graphene/ $\text{NH}_2\text{-C}_x\text{H}_{x+2}$ /GaO<sub>x</sub>/EGaIn junctions (SAMs 1–3). The  $J$ - $V$  characteristics for each type of SAM were collected from at least 80  $J$ - $V$  curves obtained on at least two independent samples prepared using the same method. Due to the large HOMO–LUMO gap of the alkyl backbones, electron transport in the junction occurs *via* coherent tunneling.<sup>53</sup> Fig. 3(a) illustrates the statistical distribution of conductances ( $G$ ) at zero bias, derived from numerical differentiation for different alkyl linker junctions. The conductance value exponentially decreases with an increase in the number of CH<sub>2</sub> units, as evidenced by the conductance–bias voltage ( $G$ - $V$ ) curves shown in Fig. S52(a) (ESI<sup>†</sup>).

One of the major challenges encountered when studying molecular transport using the EGaIn method is the significantly smaller effective electric contact area between the EGaIn tip and the SAMs layer compared to the physical contact area. Hence, accurately estimating the absolute conductivity of the SAM is difficult.<sup>54</sup> In this study, a unitless relative conductivity was employed instead of absolute conductivity. The measured contact conductivity of Cu/graphene/Ga<sub>2</sub>O<sub>3</sub>/EGaIn was assigned a value of 1, and the conductivity of all the junctions was expressed relative to this value. The absolute conductivity values for all the junctions (in  $\text{S cm}^{-2}$ ) are listed in Table S1 (ESI<sup>†</sup>).

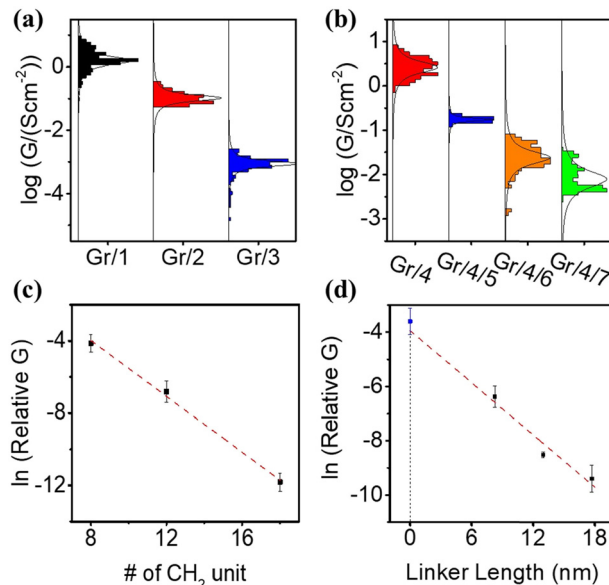


Fig. 3 (a)  $G$ - $V$  curve of Gr/SAMs/GaOx/EGaIn junction, SAMs molecule: **1**, **2** and **3**; (b)  $G$ - $V$  curve of Gr/SAMs/GaOx/GaIn junction, SAMs molecule: **4**, **4/5**, **4/6** and **4/7**. (c) Plot of  $\ln(G)$  vs. number of alkyl unit for SAM **1**–**3**. (d) Plot of  $\ln(G)$  vs. linker length for SAM **4**, **4/5**, **4/6** and **4/7**. Note relative conductance (relative  $G$ ) is used in (c) and (d), the definition of relative  $G$  is explained in main text.

Fig. 3(c) shows a plot of  $\ln(G)$  vs. the numbers of CH<sub>2</sub> units. The linear relationship between  $\ln(G)$  and molecular length confirms that transport is in the tunneling regime *via* expression:

$$\ln(G) = \ln(G_0) - \beta d$$

$G$  the measured conductance,  $G_0$  the contact conductance at  $d = 0$ ,  $d$  is the molecular length and  $\beta$  the tunneling decay factor related with tunneling barrier height.<sup>55,56</sup> The calculated  $\beta$  value was  $0.8 \pm 0.2$  per alkyl unit. This value is comparable with, but slightly lower than, reported experimental and theoretical values on single molecule junctions with similar structures (0.9–1 per alkyl unit),<sup>57</sup> which could be due to the presence of defects in the SAMs.<sup>58</sup>

The fitted relative contact conductivity at  $d = 0$  ( $G_0$ ) for alkyl-based SAMs on graphene was determined to be  $9.0 \pm 3.4$ . This value represents an order of magnitude increase compared to the measured contact conductivity (1). We attribute this difference to the complex contact interface between EGaIn and graphene, as the measurements were conducted under ambient conditions where contaminants, such as a thin film of water, can significantly reduce the measured current. In contrast, SAMs on graphene do not exhibit this issue due to their hydrophobic nature, which protects the surface from water contamination. As a result, SAM-modified graphene provides a more uniform contact and yields higher contact conductance.<sup>59</sup>

The electric behavior of the multi-component conjugated SAM-based junctions Gr/4/5, Gr/4/6 and Gr/4/7 were measured, with statistical results obtained from 80  $J$ - $V$  curves achieved on at least 2 independent samples (Fig. S51(b), ESI<sup>†</sup>). The corresponding





numerical differential conductances at zero bias are shown in Fig. 3(b) (corresponding curves in Fig. S52(b), ESI†). The electric conductivity for the pyridine based oligo-phenyl linkers (molecule 5, 6 and 7) was expected to be higher than the alkyl linkers (molecule 1, 2, and 3) with similar lengths, because the delocalized electrons in the  $\pi$  system facilitate the electron transport process.<sup>60</sup> However, the measured relative conductivity,  $G$ , for bipyridyl linker (Gr/4/5) was  $(1.7 \pm 0.7) \times 10^{-3}$ , which was 10 times lower than the measured conductivity of an alkyl chain with similar tunneling lengths (Gr/1,  $(1.6 \pm 0.4) \times 10^{-2}$ ). This could be explained by three reasons: (1) the molecular packing density of the Gr/1 junction was determined by the surface area occupied by the alkyl chain. Conversely, the packing density of Gr/4/5 was determined based on the coverage area of molecule 4, which is established to be approximately 10–20 times larger than that of alkyl chains.<sup>23,61</sup> Consequently, the number of parallel molecules per unit area formed with an EGaIn tip for Gr/4/5 was about 10–20 times lower than that of Gr/1. (2) For Gr/1, electrons tunnel through the amine–graphene interface directly, but for Gr/4/5 there were two interfacial tunnel barriers: the barrier between graphene and molecule 4, and the barrier between molecule 4 and molecule 5, which decreases the electron transmission probability. (3) In the Gr/4/5 junction, the molecular backbones (5) are isolated, thus the intermolecular transport path, which is known to increase electron transport efficiency,<sup>62</sup> is absent.

The estimated tunneling decay factor for the pyridine based oligo-phenyl system was  $0.33 \pm 0.1$  per nm (Fig. 3(d)), which is comparable with the formerly reported values on oligo-phenylene junction<sup>63</sup> and other conjugated junctions,<sup>64,65</sup> and significantly lower than that of alkyl based SAMs (Gr/1–3). This is expected, because of its smaller HOMO–LUMO gap. The fitted contact conductance for Gr/4/ $X$  ( $X = 5, 6, 7$ ) junctions at  $d = 0$ , is calculated to be  $(G_0 = 1.8 \pm 0.4) \times 10^{-2}$ . This value agrees well with the measured Gr/4 junction without a pyridine linker, which is  $(2.6 \pm 0.7) \times 10^{-2}$ .

### Investigation of thermoelectric behavior

The thermoelectric properties of SAMs were investigated using a similar EGaIn setup, but with a Peltier stage and two thermocouples to control and measure the temperature difference ( $\Delta T$ ), and a differential voltage pre-amplifier to measure the thermovoltage created by  $\Delta T$  ( $V_{\text{Therm}}$ ). The Seebeck coefficient of junction,  $S$ , was obtained *via* equation:<sup>7,8,35</sup>

$$V_{\text{Therm}} = -S \times \Delta T$$

For each sample,  $V_{\text{Therm}}$  from 5 different  $\Delta T$ s were obtained, and linear curve fit was made between  $V_{\text{Therm}}$  and  $\Delta T$  for the 5 points. The negative of the slope of the curve was the Seebeck coefficient of the junction Fig. 4(a) shows the measured Seebeck distributions of alkyl junctions on graphene substrates, with different chain lengths. Each type of junction was measured on at least two independent samples prepared with the same recipe, and on each sample at least 3 independent spots were measured. For all the samples, good linearity between  $V_{\text{Therm}}$  and  $\Delta T$  was observed (Fig. S53–S59, ESI†). The slopes of

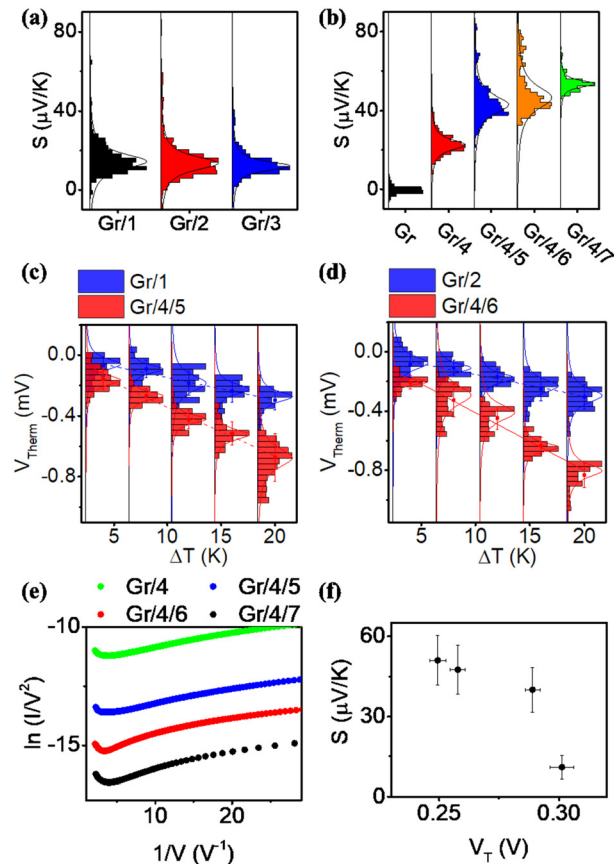


Fig. 4 Thermoelectric properties of molecular junctions. (a) and (b) Statistics of Seebeck coefficient for all measured junctions. (c) and (d) Plots of  $V_{\text{Therm}}$  vs.  $\Delta T$  for molecular junctions with comparable tunneling distance. (e) The Fowler Nordheim plot (FN) for Gr/4 and Gr/4/ $X$  ( $X = 5-7$ ) junctions. (f) Measured Seebeck vs. transition voltage for Gr/4 and Gr/4/ $X$  ( $X = 5-7$ ) junctions.

linear fits for all junctions were negative, and therefore the Seebeck coefficients of the junctions were positive. This means that the electrode Fermi level was located closer to the HOMO resonance of molecular orbital.<sup>16,35</sup> The Seebeck coefficients for 1–3 (C8, C12 and C18), junctions were  $16.5 \pm 8 \mu\text{V K}^{-1}$ ,  $14 \pm 9.5 \mu\text{V K}^{-1}$  and  $13.5 \pm 8 \mu\text{V K}^{-1}$  respectively, which are similar to the results reported by Yoon's group on the same system ( $8-15 \mu\text{V K}^{-1}$ ).<sup>35</sup> It is important to mention that in Yoon's work,<sup>35</sup> the Seebeck decreased with increasing alkyl chain lengths, whereas in the present work, the Seebeck coefficients for alkyl chains with different chain lengths were similar and within the standard deviation interval, no clear chain length-Seebeck dependency was observed. We believe it is due to the influence of the graphene on the Fermi level alignment relative to the molecular orbital energies. The Seebeck coefficient is depending on the change of transmission probability nearby Fermi region *via* the equation:

$$S \propto \frac{d}{dE} \ln(T)_{E=E_{\text{Fermi}}}$$

For a derivation and discussion of the physical meaning of this equation, see Chapter 7 of the textbook.<sup>66</sup>



In our case, the electrode Fermi level is in the middle of the large HOMO–LUMO gap of the alkyl molecules, so the change of transmission slope is small and insensitive to the change the number of alkyl units.

Fig. 4(b) illustrates the measured Seebeck distribution of all conjugated molecular junctions on graphene substrates using a first layer of ZnTPP (molecule 4) as a footprint. The Seebeck coefficient for a ZnTPP layer adsorbed on graphene without the growth of a conjugated backbone (molecules 5–7) was determined to be  $19 \pm 4.4 \mu\text{V K}^{-1}$ , which is approximately two times higher than that observed for ZnTPP on an Au substrate.<sup>23</sup> Following the growth of second-layer pyridine-based conjugated backbones with varying lengths, the Seebeck coefficients increased to  $40 \pm 8.4 \mu\text{V K}^{-1}$  (Gr/4/5),  $47.5 \pm 9.1 \mu\text{V K}^{-1}$  (Gr/4/6), and  $51 \pm 9.2 \mu\text{V K}^{-1}$  (Gr/4/7). These values are about three times higher than those of alkyl linkers with comparable film thicknesses (Fig. 4(c) and (d)). This enhanced Seebeck behavior can be attributed to the fact that compared to alkyl chains, the conjugated oligo backbones have smaller HOMO–LUMO gaps, resulting in a steeper transmission slope near the electrode Fermi energy. It is worth mentioning that while pyridine-anchored molecules typically exhibit LUMO-dominated transport in metallic nanogaps, the pyridine backbone in this study displayed HOMO-dominated behaviour. This distinction arises from the presence of a series of interfaces in the Cu/Gr/4/X (X: 5–7)/GaOx/EGaIn junction, making the interfacial transport more intricate than direct metallic contact, and significantly influenced the energy-level alignment.

The measured Seebeck coefficients for Gr/4/X (X: 5, 6, 7) junctions were found to be higher than the Seebeck coefficients reported for most molecular (or SAM-based) junctions on gold substrates, which typically range from  $5 \mu\text{V K}^{-1}$  to  $30 \mu\text{V K}^{-1}$  in absolute value (as summarized in Table S3, ESI†). Specifically, when compared with thiol-anchored oligo-phenyl ring junctions on gold substrates at both the single molecule<sup>67</sup> and SAM<sup>68</sup> scales ( $S \sim 8\text{--}13 \mu\text{V K}^{-1}$ ), where strong interfacial coupling occurs between the molecule and the substrate, the Seebeck coefficient achieved in this study was increased by about a factor of five. This enhancement can be attributed to the positioning of the Fermi level of the junctions in close proximity to the HOMO resonance, as indicated by our quantum calculations (Fig. S22, ESI†). In such a scenario, the presence of weak  $\pi$ – $\pi$  interactions and the pyridine/Zn slippery interaction contribute to a reduction in the broadening of the HOMO and LUMO peaks. Consequently, this leads to a steepening of the transmission curve at the Fermi level, ultimately resulting in a high Seebeck coefficient. It is worth noting that the measured Seebeck coefficient in this work is significantly higher than our previously reported result for the Au/conjugated SAMs/ZnTPP/graphene/Pt junction ( $|S| \sim 10\text{--}20 \mu\text{V K}^{-1}$ ).<sup>14</sup> This difference arises, because in the present study, the molecular backbones are separated rather than closely packed, thereby suppressing the intermolecular couplings between the conjugated backbones. It has been demonstrated that different intermolecular coupling regimes can cause significant shifts in the transmission curves and influence the Seebeck

coefficient of the junction.<sup>69</sup> Additionally, it should be noted that the bottom electrode in this work is single-layer graphene, which possesses a different band structure compared to the previous study where multi-layered graphene was employed as the top electrode.<sup>70</sup>

Fig. 4(e) is the Fowler Nordheim plot (FN) for Gr/4 and Gr/4/X (X: 5–7) junctions. FN plots are a useful method for estimating the energy difference between the Fermi level and the nearest molecular frontier orbital. The minimum  $V$  for  $1/V$  vs.  $I/V^2$  from the FN plot corresponds to the energy where transport changes from direct tunneling to FN tunneling, and is known as the transition voltage (VT). The transition voltage is not able to reveal if the Fermi level is closer to the HOMO or the LUMO, but can reveal the energy difference between the frontier orbital and the Fermi level. Fig. 4(f) showed the plot of measured Seebeck vs. transition voltage for Gr/4 and Gr/4/X (X: 5–7) junctions, and negative relationship was observed. This agreed with previous argument: as the number of oligo phenyl rings is increased, the Fermi-level moves closer to the HOMO resonance, which results in a decrease of the transition voltage and an increase of the Seebeck coefficient (the relationship between transition voltage and different junction was shown in Fig. S63, ESI†).

Fig. S61 (ESI†) shows the relationship between the measured current (in log scale, bias at 0.1 V) and thermovoltage of a Gr/4/5 molecular junction at  $\Delta T = 4$  K. The difference in current intensity is due to the different junction area between the probe and molecules (Fig. S40, ESI†). For junctions exhibiting low current, the thermovoltage is in the range of  $-120$  to  $200 \mu\text{V}$  (corresponding to  $30\text{--}50 \mu\text{V K}^{-1}$ ). If a junction exhibits high current ( $\log(I) > 0$ ), the thermovoltage is significantly lower (about  $10 \mu\text{V}$ ). This value is similar to the Seebeck coefficient of Gr/EGaIn junctions, which indicates the presence of a short circuit between the tip and graphene, due to defects in the SAM layer for large-area junctions.<sup>68</sup> The stability of the Gr/4/5 layer was tested by measuring the  $JV$  response for the freshly prepared sample and the sample leaving in air for 1 week. These were found to be almost identical, which indicates that the molecular layer is stable for at least a week (Fig. S60(a), ESI†). On the other hand, leaving the sample in air for 1 month caused the current density to increase significantly, indicating that the monolayer is no longer stable in the longer term, without encapsulation (Fig. S60(b), ESI†).

### Theoretical simulations

To understand how the use of a graphene electrode affects the sign and magnitude of the Seebeck coefficient, we now compute the Seebeck coefficient of metal–molecule–metal and Gr–molecule–metal junctions. Although it is of interest to choose the metal to be EGaIn, in practice EGaIn (along with its unknown oxide layer) is too complicated to model reliably. Therefore, in what follows, we choose the metal to be gold. The use of gold, rather than EGaIn is in part supported by that fact that they have similar Fermi energies, because the work function of EGaIn was about 4.3 eV, which is close to the gold work function (4.8 eV).



The transport properties of 16 junctions composed of monolayers and bilayers were modelled using a combination of density functional theory (DFT) and quantum transport theory. To calculate the electrical transport through monolayers 1–4, and bilayers 4/5, 4/6 and 4/7, we modelled junctions formed from the single molecules shown in Fig. S1 (ESI†) and the molecular bilayers shown in Fig. S2 (ESI†) (for more details see Section 1.1 in the ESI†).

As a first step towards understanding their electronic properties, their frontier orbitals and their energies were computed, as shown in Fig. S3–S9, ESI† (single molecules) and Fig. S10–S12, ESI† (molecular bilayers). Since we are studying multiple molecules with two different electrode materials, it is necessary to initially determine the optimal separation distance between these segments. Fig. S13–S19 (ESI†), show the binding energies between electrodes and molecules as a function of their separation. The optimum distances between the two components correspond to the energy minima of these curves and are summarized in Table S1 (ESI†), (for more details see Section 1.3 in the ESI†).

Fig. S20 and S21 (ESI†) show the 8 Au–Au and 8 Gr–Au junctions, of interest. Fig. S22–S27 (ESI†) show the transmission coefficients  $T(E)$  curves of the 8 Au–Au junctions. For single-molecule junctions (except ZnTTP), the simulations were non-spin-polarised, whereas for junctions containing ZnTTP, spin-polarised simulations were carried out. A similar approach is taken for Gr–Au junctions as shown in Fig. S28–S33, (for more details see Section 1.5 in the ESI†).

**Table 1** Electric properties of the studied junctions. Experimental relative conductance per area (EGaIn), and theoretical relative conductance (DFT)

| Junction | EGaIn experiment      | Std                | DFT                  |
|----------|-----------------------|--------------------|----------------------|
|          | Relative $G$ per area | (%)                | ( $G/G_0$ )          |
| Gr/1     | $1.6 \times 10^{-2}$  | $4 \times 10^{-3}$ | $1.9 \times 10^{-2}$ |
| Gr/2     | $1.1 \times 10^{-3}$  | $4 \times 10^{-4}$ | $9.7 \times 10^{-4}$ |
| Gr/3     | $7.4 \times 10^{-6}$  | $2 \times 10^{-6}$ | $6.5 \times 10^{-6}$ |
| Gr       | 1                     | $6 \times 10^{-2}$ | 1                    |
| Gr/4     | $2.6 \times 10^{-2}$  | $7 \times 10^{-3}$ | $1.0 \times 10^{-2}$ |
| Gr/4/5   | $1.7 \times 10^{-3}$  | $3 \times 10^{-4}$ | $1.5 \times 10^{-3}$ |
| Gr/4/6   | $2.0 \times 10^{-4}$  | $8 \times 10^{-5}$ | $1.4 \times 10^{-4}$ |
| Gr/4/7   | $8.3 \times 10^{-5}$  | $1 \times 10^{-5}$ | $2.0 \times 10^{-6}$ |

Note: Conductance is relative to graphene conductance Gr.

**Table 2** Thermoelectric properties of the studied junctions. Measured and calculated Seebeck coefficients EGaIn, and DFT respectively. Simulations at the DFT-predicted Fermi ( $E_F - E_F^{\text{DFT}} = 0$  eV)

| Junction | EGaIn                        | Std                          | DFT                          |
|----------|------------------------------|------------------------------|------------------------------|
|          | $S$ ( $\mu\text{V K}^{-1}$ ) | $S$ ( $\mu\text{V K}^{-1}$ ) | $S$ ( $\mu\text{V K}^{-1}$ ) |
| Gr/1     | 16.5                         | 8                            | 24                           |
| Gr/2     | 14                           | 9.5                          | 16.5                         |
| Gr/3     | 13.5                         | 8                            | 17                           |
| Gr       | –0.26                        | 0.2                          | –8                           |
| Gr/4     | 11                           | 4.4                          | 14                           |
| Gr/4/5   | 40                           | 8.4                          | 70                           |
| Gr/4/6   | 47.5                         | 9.1                          | 178                          |
| Gr/4/7   | 51                           | 9.2                          | 300                          |

The right-most two columns of Table S2 in the ESI† show the computed Seebeck coefficients of Gr–molecule–Au junctions are of opposite sign to those of Au–molecule–Au junctions. The results for the Gr-based junctions are reproduced in Table 2, which shows that the signs of the computed Seebeck coefficients of Gr–molecule–Au junctions are in agreement with the measured signs of experimental Gr–molecule–EGaIn junctions. (for more details see Sections 1.6 and 1.7 in the ESI†). Regarding the conductance comparison, Table 1, illustrates an excellent agreement between the theoretical Gr–molecule–Au junctions and the experimental Gr–molecule–EGaIn junctions.

## Conclusion

In this work, we demonstrate a stepwise method for fabricating multi-molecular-layer thermoelectric materials on a graphene substrate. Molecular backbones were separated with equal distances by using a ZnTPP footprint, which reduces intermolecular interactions. Results were compared with amine based non-conjugated junctions, with similar tunneling lengths. The electrical conductances of the molecular arrays exhibit a similar tunneling decay factor, as reported oligo-phenyl structures on a metal substrate. The Seebeck coefficient of the multi-component junction was about 3 times higher than the alkyl-based molecules, with comparable thickness, and higher than the Seebeck of most reported molecular junctions ( $> 40 \mu\text{V K}^{-1}$ ). This demonstrates that step-wise assembly of well-spaced molecular layers on single layered graphene is an effective strategy for achieving large-scale high thermoelectric performance organic materials. Moreover, this work not only shows the potential of precise doping of molecular wires through intermolecular spacing, but also enables conjugated molecules to assemble on a single-layer graphene substrate, offering future possibilities to control the orbital alignment of SAMs through the utilization of a bottom gate.

## Author contributions

A. I., X. W., J. W. and C. L. conceived the concept. All authors approved the final version of the manuscript.

## Conflicts of interest

There are no conflicts to declare.

## Acknowledgements

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